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## Table of Contents

### Dielectric Science and Materials

#### Hafnium Oxide Based CMOS Compatible Ferroelectric Materials

*U. Schroeder, S. Mueller, J. Mueller, E. Yurchuk,  
D. Martin, C. Adelmann, T. Schloesser, R. van Bentum,  
T. Mikolajick* ..... N69

#### The Stripping Behavior of High-Dose Ion-Implanted Photoresists in Supercritical CO<sub>2</sub> Formulations

*Bo Li, Tingting Han, Lei Wang, Qingpu Wang,  
Yuxiang Li* ..... N73

#### Effects of Ethylene/Ammonia Mixtures on Thermal Chemical Vapor Deposition Rates and Microstructures of Carbon Films

*Liang-Hsun Lai, Huei-Cheng Li, Sham-Tsong Shiue,  
Tsong-Jen Yang, Hung-Yi Lin* ..... N80

#### Low-*k* Mesoporous Pure Silica Zeolite with High Elastic Modulus Using 1,3,5,7-Tetra-Methyl-Cyclo-Tetra-Siloxane and Ultraviolet Treatments

*Tadashi Sato, Takafumi Yamamoto, Yuki Hata,  
Yutaka Seino, Yasuhisa Kayaba, Shin-Ichiro Kuroki,  
Takamaro Kikkawa* ..... N89

### Electronic Materials and Processing

#### Effects of ZnO Buffer Layer on Characteristics of ZnO:Ga Films Grown on Flexible Substrates: Investigation of Surface Energy, Electrical, Optical, and Structural Properties

*Jia-Ling Wu, Han-Yu Lin, Yu-Cheng Chen,  
Sheng-Yuan Chu, Chia-Chiang Chang,  
Chin-Jyi Wu, Yung-Der Juang* ..... P115

#### Growth Kinetics of Copper Sulfide Thin Films by Chemical Bath Deposition

*Paravee Vas-Ummuay, Chih-hung Chang* ..... P120

#### Modeling Solid Phase Epitaxial Growth for Patterned Ge Substrates

*B. L. Darby, B. R. Yates, Ashish Kumar, A. Kontos,  
R. G. Elliman, K. S. Jones* ..... P130

#### Crystalline Properties and Strain Relaxation Mechanism of CVD Grown GeSn

*F. Gencarelli, B. Vincent, J. Demeulemeester,  
A. Vantomme, A. Moussa, A. Franquet, A. Kumar,  
H. Bender, J. Meersschaut, W. Vandervorst, R. Loo,  
M. Caymax, K. Temst, M. Heyns* ..... P134

#### Relaxed and Strained Patterned Germanium-Tin Structures: A Raman Scattering Study

*Ran Cheng, Wei Wang, Xiao Gong, Linfeng Sun,  
Pengfei Guo, Hailong Hu, Zexiang Shen,  
Genquan Han, Yee-Chia Yeo* ..... P138

#### Observations of Macroporous Gallium Nitride Electrochemically Etched from High Doped Single Crystal Wafers in HF Based Electrolytes

*G. Gautier, D. Valente, J. Biscarrat, A. Yvon* ..... P146

#### Hot-Wire Generated Atomic Hydrogen and its Impact on Thermal ALD in TiCl<sub>4</sub>/NH<sub>3</sub> System

*H. Van Bui, A. Y. Kovalgin, A. A. I. Aarnink,  
R. A. M. Wolters* ..... P149

#### Study of Electronic Structure and Film Composition at the Back Channel Surface of Amorphous In-Ga-Zn-O Thin Films

*Aya Hino, Tomoya Kishi, Hiroaki Tao, Shinya Morita,  
Kazushi Hayashi, Toshihiro Kugimiya* ..... P156

#### Potassium Periodate-Based Solutions for Minimizing Galvanic Corrosion at the Cu-Mn Interface and for Polishing the Associated Cu Interconnect Structures

*Ashwin M. Chockalingam, Uma Rames K. Lagudu,  
S. V. Babu* ..... P160

#### Silicon Single Crystal Growth from a Melt: On the Impact of Dopants on the *v*/*G* Criterion

*Jan Vanhellefont, Eiji Kamiyama, Koji Sueoka* ..... P166

#### Crystallographic Texture of Submicron Thin Aluminum Nitride Films on Molybdenum Electrode for Suspended Micro and Nanosystems

*R. E. Sah, L. Kirste, H. Kirmse, M. Mildner, L. Wilde,  
S. Kopta, F. Knöbber, M. Krieg, V. Cimalla,  
V. Lebedev, O. Ambacher* ..... P180

## Wet Chemical Etching of InP for Cleaning Applications

### I. An Oxide Formation/Oxide Dissolution Model

*D. Cuypers, S. De Gendt, S. Arnauts, K. Paulussen,  
D. H. van Dorp* ..... P185

## Wet Chemical Etching of InP for Cleaning Applications

### II. Oxide Removal

*D. H. van Dorp, D. Cuypers, S. Arnauts, A. Moussa,  
L. Rodriguez, S. De Gendt* ..... P190

---

## Electronic and Photonic Devices, and Systems

---

### Photoelectrochemical Conditioning of MOVPE p-InP Films for Light-Induced Hydrogen Evolution: Chemical, Electronic and Optical Properties

*A. G. Muñoz, C. Heine, M. Lublow, H. W. Klemm,  
N. Szabó, T. Hannappel, H.-J. Lewerenz* ..... Q51

### Variation of Oxygen Deficiency in Solution-Processed Ultra-Thin Zinc-Tin Oxide Films to Their Transistor Characteristics

*Li-Chih Liu, Jen-Sue Chen, Jiann-Shing Jeng,  
Wei-Yu Chen* ..... Q59

### Preparation of Large-Aperture Macroporous Silicon with Controllable Pore Tip Angle on Low-Resistivity p-Type c-Si Substrate by Metal-Catalyzed Electrochemical Etching

*Zhaochen Li, Lei Zhao, Hongwei Diao, Hailing Li,  
Chunlan Zhou, Wenjing Wang* ..... Q65

### Antimony Chalcogenide/Lead Selenide Thin Film Solar Cell with 2.5% Conversion Efficiency Prepared by Chemical Deposition

*M. Calixto-Rodriguez, Harumi Moreno García,  
M. T. S. Nair, P. K. Nair* ..... Q69

### Dependence of Light-Accelerated Instability on Bias and Environment in Amorphous Indium-Gallium- Zinc-Oxide Thin Film Transistors

*Yu-Chun Chen, Ting-Chang Chang, Hung-Wei Li,  
Wan-Fang Chung, Tien-Yu Hsieh, Yi-Hsien Chen,  
Wu-Wei Tsai, Wen-Jen Chiang, Jing-Yi Yan* ..... Q74

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## Luminescence and Display Materials, Devices, and Processing

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### InGaN Light-Emitting Diode with a Photochemically Oxidized GaN Nanorod Structure

*Chung-Chieh Yang, Chia-Feng Lin, Jiang Ren-Hao,  
Bing-Cheng Shieh, Po-Fu Cheng, Wang-Po Tseng,  
Jing-Jie Dai* ..... R65

### Photoluminescence Properties of Red-Emitting Mn<sup>2+</sup>-Activated CaAlSiN<sub>3</sub> Phosphor for White-LEDs

*Zhijun Zhang, Anneke C. A. Delsing, Peter H. L. Notten,  
Jingtai Zhao, Pieter Dorenbos, Hubertus T. Hintzen* ..... R70

### GeSn Heterojunction Diode: Detector and Emitter in One Device

*M. Oehme, E. Kasper, J. Schulze* ..... R76

### Intense Blue Emission Phosphor BaCa<sub>2</sub>MgSi<sub>2</sub>O<sub>8</sub>: Eu<sup>2+</sup> for Fluorescent Lamps

*Dejian Hou, Wei Chen, Xuemei Ding, Hongbin Liang,  
Lirong Zheng, Jing Zhang* ..... R79

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## Miscellaneous

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### Erratum: Oxy-Fluoride Phosphors for Solid State Lighting [*ECS J. Solid State Sci. Technol.*, 2, R3088 (2013)]

*Eirin Sullivan, Thomas Vogl* ..... X3

